

# HFA16TA60CSPbF

Ultrafast, Soft Recovery Diode

#### **Features**

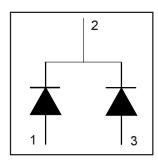
- · Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I<sub>RRM</sub>
- Very Low Q<sub>rr</sub>
- · Specified at Operating Conditions
- Lead-Free

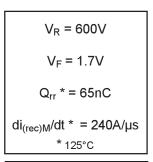
#### **Benefits**

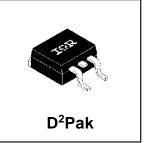
- · Reduced RFI and EMI
- · Reduced Power Loss in Diode and Switching Transistor
- · Higher Frequency Operation
- · Reduced Snubbing
- · Reduced Parts Count

### Description

International Rectifier's HFA16TA60CS is a state of the art center tap ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 8 amps per Leg continuous current, the HFA16TA60CS is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA16TA60CS is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.







#### Absolute Maximum Ratings (per Leg)

	Parameter	Max	Units
V <sub>R</sub>	Cathode-to-Anode Voltage	600	V
I <sub>F</sub> @ T <sub>C</sub> = 100°C	Continuous Forward Current	8.0	
I <sub>FSM</sub>	Single Pulse Forward Current	60	Α
I <sub>FRM</sub>	Maximum Repetitive Forward Current	24	]
P <sub>D</sub> @ T <sub>C</sub> = 25°C	Maximum Power Dissipation	36	W
P <sub>D</sub> @ T <sub>C</sub> = 100°C	Maximum Power Dissipation	14	_ vv
TJ	Operating Junction and	- 55 to +150	°C
T <sub>STG</sub>	Storage Temperature Range	- 55 10 +150	

10/07/05

### HFA16TA60CSPbF



### Electrical Characteristics (per Leg) @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
$V_{BR}$	Cathode Anode Breakdown Voltage	600			V	I <sub>R</sub> = 100μA	
V <sub>FM</sub>			1.4	1.7		I <sub>F</sub> = 8A See Fig. 1	
	Max Forward Voltage		1.7	2.1	V	I <sub>F</sub> = 16A	
			1.4	1.7		I <sub>F</sub> = 8A, T <sub>J</sub> = 125°C	
I <sub>RM</sub>	Max Reverse Leakage Current		0.3	5	μA	$V_R = V_R$ Rated See Fig. 2	
			100	500		$T_J = 125$ °C, $V_R = 0.8 \times V_R$ Rated	
C <sub>T</sub>	Junction Capacitance		10	25	pF	$V_R = 200V$ See Fig. 3	
L <sub>S</sub>	Series Inductance		8.0		nH	Measured lead to lead 5mm from	
	Series inductance		0.0			package body	

### Dynamic Recovery Characteristics (per Leg) @ T<sub>J</sub> = 25°C (unless otherwise specified)

	<u> </u>							
	Parameter	Min	Тур	Max	Units	Test Conditions		
t <sub>rr</sub>	Reverse Recovery Time		18			$I_F = 1.0A$ , $di_f/dt = 200A$	/μs, V <sub>R</sub> = 30V	
t <sub>rr1</sub>	See Fig. 5, 6 & 16		37	55	ns	$T_J = 25$ °C		
t <sub>rr2</sub>			55	90		T <sub>J</sub> = 125°C	I <sub>F</sub> = 8A	
I <sub>RRM1</sub>	Peak Recovery Current		3.5	5.0	Α	T <sub>J</sub> = 25°C		
I <sub>RRM2</sub>	See Fig. 7& 8		4.5	8.0	^	T <sub>J</sub> = 125°C	V <sub>R</sub> = 200V	
Q <sub>rr1</sub>	Reverse Recovery Charge		65	138	nC	T <sub>J</sub> = 25°C		
Q <sub>rr2</sub>	See Fig. 9 & 10		124	360	110	T <sub>J</sub> = 125°C	di <sub>f</sub> /dt = 200A/µs	
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current		240		A/µs	T <sub>J</sub> = 25°C		
di <sub>(rec)M</sub> /dt2	During t <sub>b</sub> See Fig. 11 & 12		210		-Λ/μS	T <sub>J</sub> = 125°C		

### **Thermal - Mechanical Characteristics**

	Parameter	Min	Тур	Max	Units
T <sub>lead</sub> ①	Lead Temperature			300	°C
R <sub>th</sub> JC	Junction-to-Case, Single Leg Conducting			3.5	
	Junction-to-Case, Both Legs Conducting			1.75	K/W
R <sub>thJA</sub> @	Thermal Resistance, Junction to Ambient			80	
Wt	Weight		2		g
			0.07		(oz)
	Mounting Torque	6		12	Kg-cm
		5		10	lbf•in

 $<sup>\</sup>odot$  0.063 in. from Case (1.6mm) for 10 sec

② Typical Socket Mount

# International TOR Rectifier

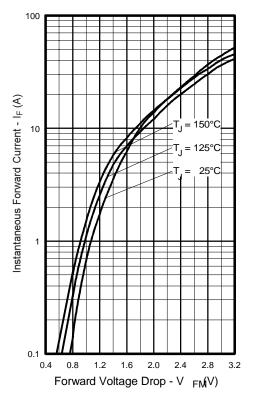


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current, (per Leg)

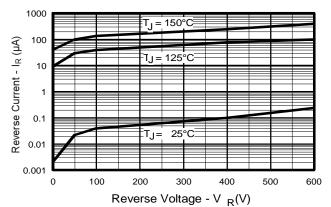
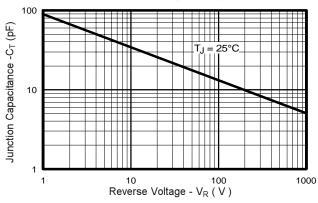


Fig. 2 - Typical Reverse Current vs. Reverse Voltage, (per Leg)



**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage, (per Leg)

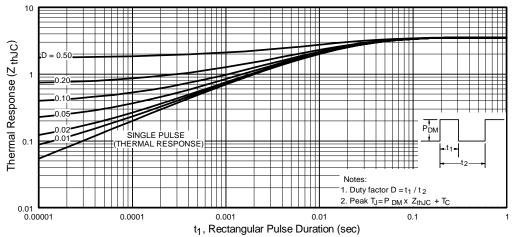


Fig. 4 - Maximum Thermal Impedance Z<sub>thic</sub> Characteristics, (per Leg)

# International TOR Rectifier

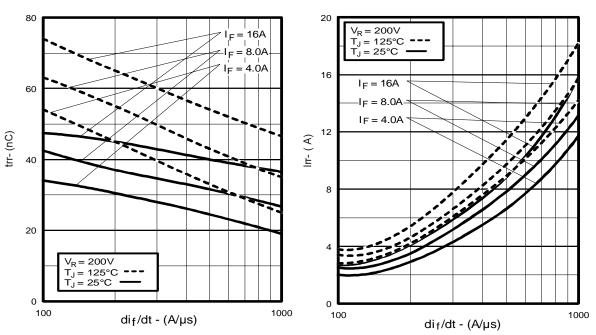
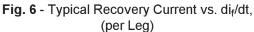


Fig. 5 - Typical Reverse Recovery vs. di<sub>f</sub>/dt, (per Leg)



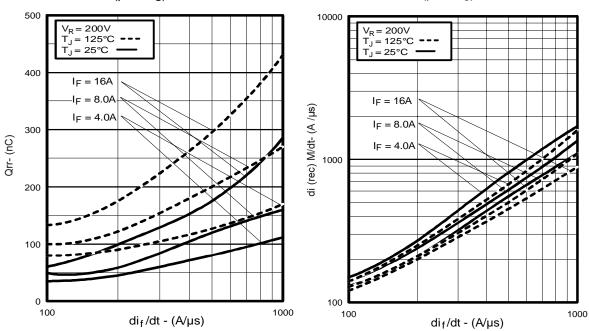


Fig. 7 - Typical Stored Charge vs. di<sub>f</sub>/dt, (per Leg)

Fig. 8 - Typical  $di_{(rec)M}/dt$  vs.  $di_f/dt$ , (per Leg)

Document Number: 94059

# International TOR Rectifier

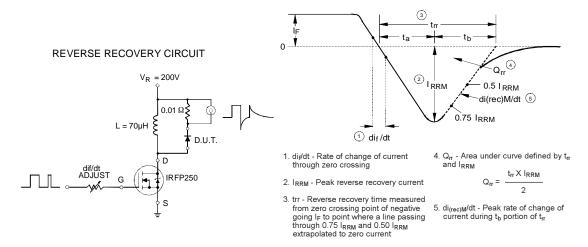


Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

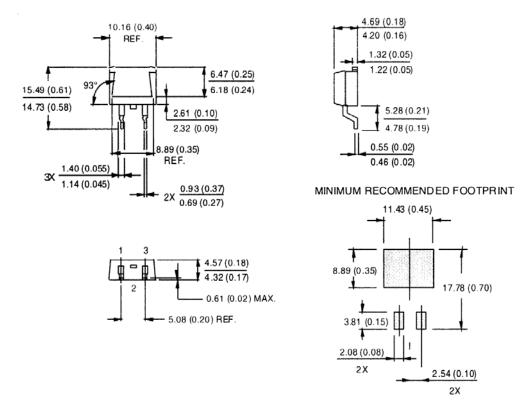
### HFA16TA60CSPbF

International

TOR Rectifier

# D<sup>2</sup>PAK Package Outline

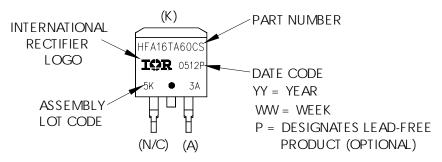
Dimensions are shown in millimeters (inches)



# Conforms to JEDEC Outline D<sup>2</sup>PAK Dimensions in millimeters and inches

# D<sup>2</sup>PAK Part Marking Information

EXAMPLE: THIS IS A HFA16TA60CS

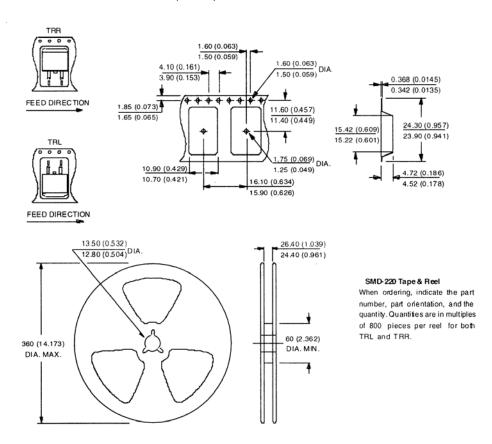


Document Number: 94059 www.vishay.com



### D<sup>2</sup>PAK Tape & Reel Information

Dimensions are shown in millimeters (inches)



Data and specifications subject to change without notice. This product has been designed and qualified for the Consumer market.

Qualifications Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105

TAC Fax: (310) 252-7903

10/05

Document Number: 94059 www.vishay.com



Vishay

### **Notice**

The products described herein were acquired by Vishay Intertechnology, Inc., as part of its acquisition of International Rectifier's Power Control Systems (PCS) business, which closed in April 2007. Specifications of the products displayed herein are pending review by Vishay and are subject to the terms and conditions shown below.

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

International Rectifier®, IR®, the IR logo, HEXFET®, HEXSense®, HEXDIP®, DOL®, INTERO®, and POWIRTRAIN® are registered trademarks of International Rectifier Corporation in the U.S. and other countries. All other product names noted herein may be trademarks of their respective owners.

Document Number: 99901 www.vishay.com
Revision: 12-Mar-07 1